

SILICON TRANSISTORS 2SC4942

NPN SILICON TRIPLE DIFFUSED TRANSISTOR FOR HIGH-SPEED HIGH-VOLTAGE SWITCHING

The 2SC4942 is a transistor developed for high-speed high-voltage switching. This transistor is ideal for use in switching devices such as switching regulators and DC/DC converters.

FEATURES

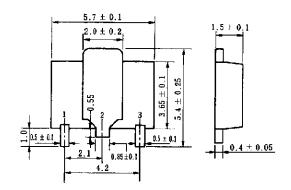
- New package with dimensions in between those of small signal and power signal package
- · High voltage
- · Fast switching speed
- · Complementary transistor with the 2SA1871

QUALITY GRADES

Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

PACKAGE DRAWING (UNIT: mm)



Electrode connection

- 1. Emitter
- 2. Collector
- 3. Base

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	Vсво		600	V
Collector to emitter voltage	VCEO		600	٧
Emitter to base voltage	V _{EBO}		7.0	V
Collector current (DC)	I _{D(DC)}		1.0	Α
Collector current (pulse)	ID(pulse)	PW ≤ 10 ms, duty cycle ≤ 50 %	2.0	Α
Total power dissipation	Рт	$7.5~\text{cm}^2 \times 0.7~\text{mm}$ ceramic board mounted	2.0	W
Junction temperature	Tj		150	°C
Storage temperature	T _{stg}		-55 to +150	°C

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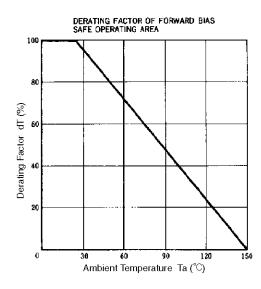
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

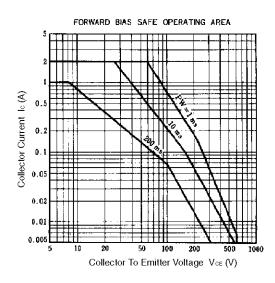
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	VcB = 600 V, IE = 0			10	μΑ
Emitter cutoff current	ІЕВО	V _{EB} = 7.0 V, I _C = 0			10	μΑ
DC current gain	h _{FE1}	VcE = 5.0 V, Ic = 0.1 A	30	55	120	_
DC current gain	h _{FE2}	VcE = 5.0 V, Ic = 0.5 A	5	10		_
Collector saturation voltage	V _{CE(sat)}	Ic = 400 mV, I _B = 80 mA		0.35	1.0	V
Base saturation voltage	V _{BE(sat)}	Ic = 400 mV, I _B = 80 mA		0.9	1.2	V
Gain bandwidth product	f⊤	VcE = 5.0 V, IE = -50 mA		30		MHz
Output capacitance	Cob	VcB = 10 V, IE = 0, f = 1.0 MHz		15		pF
Turn-on time	ton	Ic = 0.5 A, Vcc= 250 V		0.1	0.5	μs
Storage time	tstg	$I_{B1} = -I_{B2} = 0.1 \text{ A}$ $R_L = 500 \Omega$		4.0	5.0	μs
Fall time	tf			0.2	0.5	μs

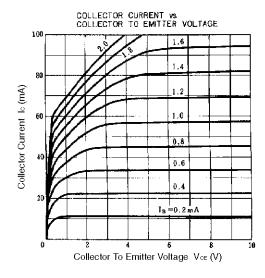
hfe CLASSIFICATION

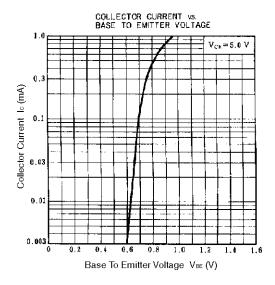
Marking	AA1	AA2	AA3	
h _{FE1}	30 to 60	40 to 80	60 to 120	

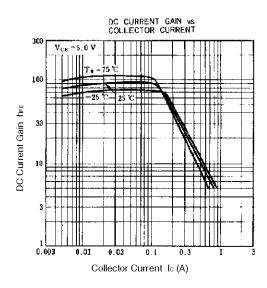
TYPICAL CHARACTERISTICS (Ta = 25°C)

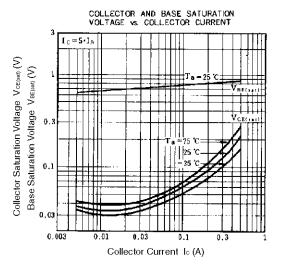


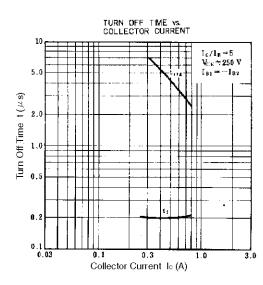


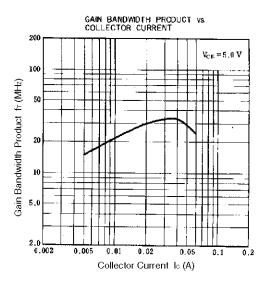




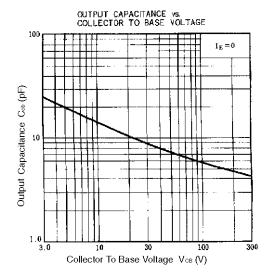








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